

SPEC. No. DG

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CONPOUND SEMICONDUCTOR DEVICES DIV

ELECTRONIC COMPONENTS GROUP

SHARP CORPORATION

Technical literature

DEVICE SPECIFICATION FOR

LIGHT EMITTING DIODE

MODEL No.

GM5BW01300A

Specified for

CUSTOMERS' APPROVAL

Date

By

PRESENTED

Date By

M.Katoh, Department General Manager of Electronic Components Group SHARP CORPORATION



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# PRODUCT NAMELight Emitting DiodeMODEL NO.GM5BW01300A

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2. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets, as well as the precautions mentioned below. Sharp assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets, and the precautions mentioned below.

#### (Precautions)

- (1) This products is designed for use in the following application areas;
  - \* OA equipment \* Audio visual equipment \* Home appliance
  - \* Telecommunication equipment (Terminal) \* Measuring equipment
  - \* Tooling machines \* Computers

If the use of the product in the above application areas is for equipment listed in paragraphs (2) or (3), please be sure to observe the precautions given in those respective paragraphs.

(2) Appropriate measures, such as fail-safe design and redundant design considering the safety design of the overall system and equipment, should be taken to ensure reliability and safety when this product is used for equipment which demands high reliability and safety in function and precision, such as ;

\* Transportation control and safety equipment (aircraft, train, automobile etc.)

- \* Traffic signals \* Gas leakage sensor breakers \* Rescue and security equipment \* Other safety equipment
- (3) Please do not use this product for equipment which require extremely high reliability and safety in function and precision, such as ;

\* Space equipment \* Telecommunication equipment (for trunk lines)

- \* Nuclear power control equipment \* Medical equipment
- (4) Please contact and consult with a Sharp sales representative if there are any questions regarding interpretation of the above three paragraphs.
- 3. Please contact and consult with a Sharp sales representative for any questions about this product.

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HARP	Reference		
<u>GM5BW01300A spec</u>	ification_		
1. Application			
This specification applies to the light emitting di-	ode device Model No.GM5BW013	800A	
[InGaN/SiC Blue chip + Phosper LED device]			
2. Outline dimensions and terminal connections	Refer to the attached sheet Page	3.	
3. Ratings and characteristics	Refer to the attached sheet Page 4	I ∼ 6.	
3-1. Absolute maximum ratings			
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6-1. Precautions matters for designing circuit			
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#### 3.Ratings and characteristics

### 3-1. Absolute maximum ratings

	<u>, .</u>		(Ta=25 ℃)		
Parameter	Symbol	Rating	Unit		
Power dissipation	Р	400	mW		
Continuous forward current(*1)	I <sub>F</sub>	50	mA		
Peak forward current(*2)	I <sub>FM</sub>	120	mA		
Devetine frater	DC	0.83	mA/℃		
Derating factor	Pulse	2.00	mA/℃		
Reverse voltage	V <sub>R</sub>	5	V		
Operating temperature	Topr	-30 to +85	°C		
Storage temperature	Tstg	-40to +85	°C		
Soldering temperature (*3)	Tsol	295	°C		
Electrostatic Discharge Threshhold (Humanbody mode)	HBM	1000	V		

(\*1) Rating of each chip. Using plural chips, within power disspation.

(\*2) Duty ratio = 1/20, Pulse width = 0.1 s

(\*3) Manual Soldering Max. 3 seconds.

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Forward Voltage <sup>*</sup> 4	V <sub>F</sub>		-	3.4	4.5	V
Luminous intensity*5 (3 chips lit on)	I <sub>V</sub>	I <sub>F</sub> =35 mA	-	4	-	cd
	region		x	у		
chromaticity*6 (typ.)			0.31	0.31		
Reverse Current <sup>*</sup> 4	I <sub>R</sub>	V <sub>R</sub> =4V	-	-	100	μΑ

(\*4) Rating of each chip

(\*5) Measured by EG&G MODEL550(Radiometer/Photometersystem) after 20ms drive (Tolerance : ±15%)

(\*6) Measured by Ohtsuka electronics MODEL MCPD-2000 after 9.6ms drive (Tolerance : x,y:±0.02) DG~045008 Page

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(Ta=25 ℃)





(\*1) Above characteristics data are typical data and not a guaranteed data

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### 4. Reliability

The reliability of products shall be satisfied with items listed below.

4-1.	Test items and test	conditions	Confid	ence leve	el: 90%
No.	Test items	Test conditions	Samples	Defective	LTPD
			n	С	(%)
1	Temperature	-40 °C(30 min)~+85 °C(30 min),30 times			
	cycle		22	0	10
2	High temp and high	$T_a=+60$ °C, RH=90 %, t=1 000 h			
	humidity storage		22	0	10
3	High temperature	$Ta=85^{\circ}C, t=1\ 000\ h$			
	storage		22	0	10
4	Low temperature	$Ta=-40^{\circ}C$ , t=1 000 h			
	storage		22	0	10
5	Operating test	Ta=25 °C, IF=35mA, t=1 000 h			:
1			22	0	10
6	Mechanical shock	$15\ 000\ \mathrm{m/s^2},\ 0.5\ \mathrm{ms}$			
	test	$\pm X \cdot \pm Y \cdot \pm Z$ direction. 3 times	11	0	20
7	Variable frequency	$200 \text{ m/s}^2$ , $100 \sim 2\ 000 \sim 100 \text{ Hz}$ / sweep for 4 min.			
	vibration	X·Y·Z direction, 4 times	11	0	20
8	Soldering heat	Refer to the attached sheet, Page 12/13, 2 times			
	·		11	0	20
9	Solder ability	240±5℃, 5s			
	(Dip Method)	Prior disposition : Dip in login flux.	11	0	20

4-2. Failure judgement criteria (\*1)

4-2-1 Temperature cycle, High temp and high humidity storage, High temperature storage, Low temperature storage, Operating test, Mechanical shock test, Variable frequency vibration, Soldering heat

	Soldering heat		
No.	Parameter	Symbol	Failure judgement criteria (*2)
1	Forward voltage	VF	$V_F > U.S.L \times 1.2$
2	Reverce current	I <sub>R</sub>	$I_R > U.S.L \times 2.0$
3	Luminous intensity	Iv	$Iv \le Initial value \times 0.5$ , $Iv \ge Initial varue \times 2.0$

\*1 : Measuring condition is accordance with specification.

\*2 : U.S.L. is shown by Upper Specification Limit.

### 4-2-2 Solder ability

Solder shall be adhere at the area (The slant line part and back of the lead) of 95% or more of dipped portion.

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## 5. Supplement

5-1. Taping

5-1-1. Shape and dimension of tape (Ref.)



Parameter		Symbol	Dimension [mm] (Ref.)	Remarks		
Concave squaret	Vertical	А	6.4	Dimension excludea corner R at inside bottom		
hole for part	Horizontal	В	7.4			
insertion	Pitch	P 1	8.0			
Round	Diameter	D <sub>0</sub>	1, 55			
sprocket	Pitch	P <sub>0</sub>	4.0	Accumulated error ±0.5mm/10 pitch		
hole	Position	E	1.75	Distance between tape edge and hole center		
Center to center	Vertical	$P_2$	2.0	Center line of the concave square hole and		
distance	Horizontal	F	7.5	round sprocket hole		
	Width	W 1	14.0			
Cover tape	Thickness	tg	0.1			
	Width	Wo	16.0			
Carrer tape	Thickness	t 1	0.3			
Thickness of ent	ire unit	t <sub>2</sub>	1.75	With cover tape and carrier tape combined		

5-1-2. Shape and dimension of reel (Ref.)



Par	ameter		Symbol	Dimension [mm](Ref.)	Remarks
	Diameter		A	φ 178	
Frange	Thickness		t	1.5	
0	Inner spac	e direction	W	17.5	Dimension of shaft core
	External diameter		В	φ 60	
Hub	Spindle hole diameter		С	φ 13	
	Key slit	Width	E	2.0	
		Depth	U	4.5	
Notation for part name etc.			Labeling on the	side of the frange.(part	name, quantity, lot No.)



(2) in individual (on PWB or metallic tray)

Temprature: 100°Cto120°C, Time: more than 12 hours



#### 5-4. Environment

5-4-1. Ozonosphere destructive chemicals.

- (1) The device doesn't contain following chemicals.
- (2) The device doesn't have a production line whose process requires following chemicals. Banned chemicals : CFCs,halones, CCl<sub>4</sub>, Trichloroethane(Methylchloroform)

5-4-2. Bromic non-burning materials

The device doesn't contain bromic non-burning materials(PBBOs,PBBs)



 $\sim 160$   $1 \sim 4$  °C/s  $\sim 90 \sim 120s.$   $\rightarrow$  max

Jemperature (°C)

Time(s)

5 s

Fig. Reflow soldering temperature profile



Test the cleaning method under actual conditions and check for abnormalities before actual use.

(2) Solvents

Use only the following types of solvent. And dry it rapidly after cleaning.

water, ethyl alcohol, isopropyl alcohol

Recommend conditions: R.T. 40kHz, 30W/l, 3 to 4 minutes